

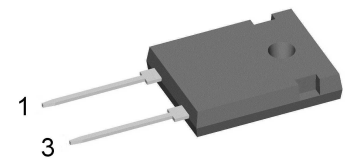


Sonic Fast Recovery Diode

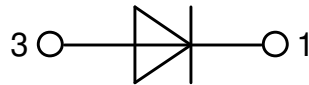
$V_{RRM} = 1800\text{ V}$
 $I_{FAV} = 40\text{ A}$
 $t_{rr} = 300\text{ ns}$

High Performance Fast Recovery Diode
 Low Loss and Soft Recovery
 Single Diode

Part number
DH40-18A



Backside: cathode



Features / Advantages:

- Planar passivated chips
- Very low leakage current
- Very short recovery time
- Improved thermal behaviour
- Very low I_{rm}-values
- Very soft recovery behaviour
- Avalanche voltage rated for reliable operation
- Soft reverse recovery for low EMI/RFI
- Low I_{rm} reduces:
 - Power dissipation within the diode
 - Turn-on loss in the commutating switch

Applications:

- Antiparallel diode for high frequency switching devices
- Antisaturation diode
- Snubber diode
- Free wheeling diode
- Rectifiers in switch mode power supplies (SMPS)
- Uninterruptible power supplies (UPS)

Package: TO-247

- Industry standard outline
- RoHS compliant
- Epoxy meets UL 94V-0

Disclaimer Notice

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| Fast Diode | | | | Ratings | | | |
|------------|--|---|-------------------------|---------|------|------------|--|
| Symbol | Definition | Conditions | min. | typ. | max. | Unit | |
| V_{RSM} | max. non-repetitive reverse blocking voltage | $T_{VJ} = 25^{\circ}C$ | | | 1800 | V | |
| V_{RRM} | max. repetitive reverse blocking voltage | $T_{VJ} = 25^{\circ}C$ | | | 1800 | V | |
| I_R | reverse current, drain current | $V_R = 1800 V$ | $T_{VJ} = 25^{\circ}C$ | | 100 | μA | |
| | | $V_R = 1800 V$ | $T_{VJ} = 125^{\circ}C$ | | 1 | mA | |
| V_F | forward voltage drop | $I_F = 40 A$ | $T_{VJ} = 25^{\circ}C$ | | 2.06 | V | |
| | | $I_F = 80 A$ | | | 2.56 | V | |
| | | $I_F = 40 A$ | $T_{VJ} = 125^{\circ}C$ | | 2.08 | V | |
| | | $I_F = 80 A$ | | | 2.79 | V | |
| I_{FAV} | average forward current | $T_C = 100^{\circ}C$ rectangular $d = 0.5$ | $T_{VJ} = 150^{\circ}C$ | | 40 | A | |
| V_{FO} | threshold voltage | } for power loss calculation only | $T_{VJ} = 150^{\circ}C$ | | 1.38 | V | |
| r_F | slope resistance | | | | 17.5 | m Ω | |
| R_{thJC} | thermal resistance junction to case | | | | 0.45 | K/W | |
| R_{thCH} | thermal resistance case to heatsink | | | 0.3 | | K/W | |
| P_{tot} | total power dissipation | | $T_C = 25^{\circ}C$ | | 280 | W | |
| I_{FSM} | max. forward surge current | $t = 10 ms; (50 Hz), sine; V_R = 0 V$ | $T_{VJ} = 45^{\circ}C$ | | 400 | A | |
| C_J | junction capacitance | $V_R = 900 V \quad f = 1 MHz$ | $T_{VJ} = 25^{\circ}C$ | | 19 | pF | |
| I_{RM} | max. reverse recovery current | } $I_F = 60 A; V_R = 900 V$ $-di_F / dt = 750 A/\mu s$ | $T_{VJ} = 25^{\circ}C$ | | 50 | A | |
| | | | $T_{VJ} = 125^{\circ}C$ | | 60 | A | |
| t_{rr} | reverse recovery time | | $T_{VJ} = 25^{\circ}C$ | | 300 | ns | |
| | | | $T_{VJ} = 125^{\circ}C$ | | 550 | ns | |



| Package TO-247 | | | Ratings | | | |
|----------------|------------------------------|--------------|---------|------|------|------|
| Symbol | Definition | Conditions | min. | typ. | max. | Unit |
| I_{RMS} | RMS current | per terminal | | | 70 | A |
| T_{VJ} | virtual junction temperature | | -55 | | 150 | °C |
| T_{op} | operation temperature | | -55 | | 125 | °C |
| T_{stg} | storage temperature | | -55 | | 150 | °C |
| Weight | | | | 6 | | g |
| M_D | mounting torque | | 0.8 | | 1.2 | Nm |
| F_C | mounting force with clip | | 20 | | 120 | N |

Product Marking



| Ordering | Ordering Number | Marking on Product | Delivery Mode | Quantity | Code No. |
|----------|-----------------|--------------------|---------------|----------|----------|
| Standard | DH40-18A | DH40-18A | Tube | 30 | 499765 |

Equivalent Circuits for Simulation

** on die level*

$T_{VJ} = 150^{\circ}C$



Fast Diode

| | | | |
|--------------|--------------------|------|----|
| $V_{0\ max}$ | threshold voltage | 1.38 | V |
| $R_{0\ max}$ | slope resistance * | 14.5 | mΩ |



Outlines TO-247



| Sym. | Inches | | Millimeter | |
|------------------|-----------|-------|------------|-------|
| | min. | max. | min. | max. |
| A | 0.185 | 0.209 | 4.70 | 5.30 |
| A1 | 0.087 | 0.102 | 2.21 | 2.59 |
| A2 | 0.059 | 0.098 | 1.50 | 2.49 |
| D | 0.819 | 0.845 | 20.79 | 21.45 |
| E | 0.610 | 0.640 | 15.48 | 16.24 |
| E2 | 0.170 | 0.216 | 4.31 | 5.48 |
| e | 0.430 BSC | | 10.92 BSC | |
| L | 0.780 | 0.800 | 19.80 | 20.30 |
| L1 | - | 0.177 | - | 4.49 |
| $\varnothing P$ | 0.140 | 0.144 | 3.55 | 3.65 |
| Q | 0.212 | 0.244 | 5.38 | 6.19 |
| S | 0.242 BSC | | 6.14 BSC | |
| b | 0.039 | 0.055 | 0.99 | 1.40 |
| b2 | 0.065 | 0.094 | 1.65 | 2.39 |
| b4 | 0.102 | 0.135 | 2.59 | 3.43 |
| c | 0.015 | 0.035 | 0.38 | 0.89 |
| D1 | 0.515 | - | 13.07 | - |
| D2 | 0.020 | 0.053 | 0.51 | 1.35 |
| E1 | 0.530 | - | 13.45 | - |
| $\varnothing P1$ | - | 0.29 | - | 7.39 |



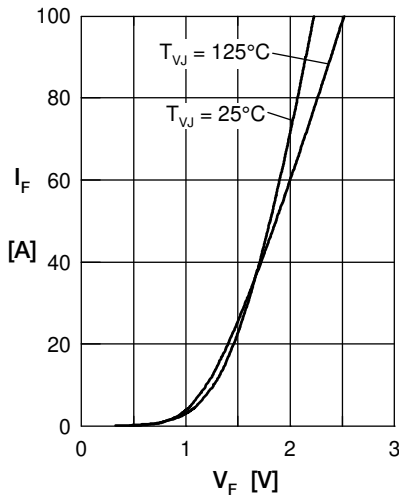
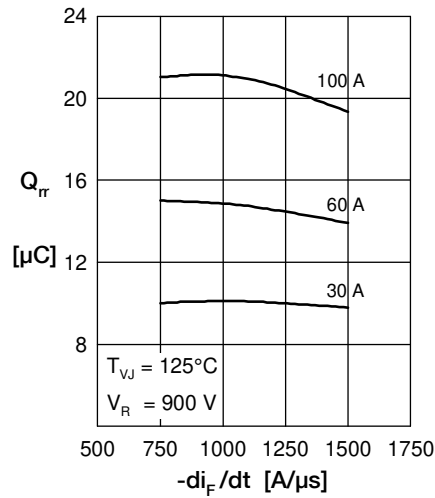
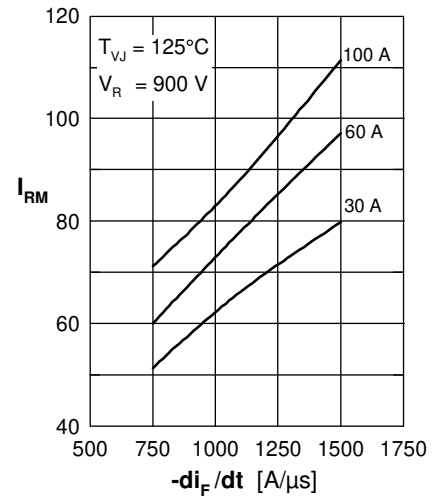
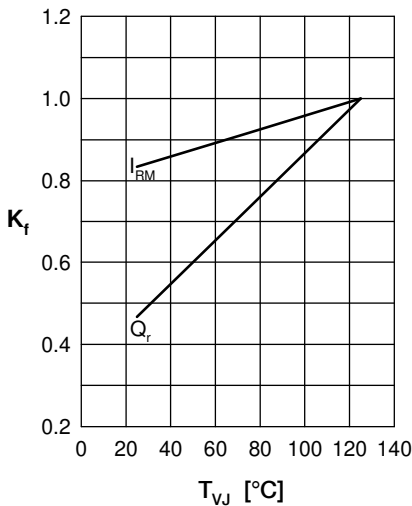
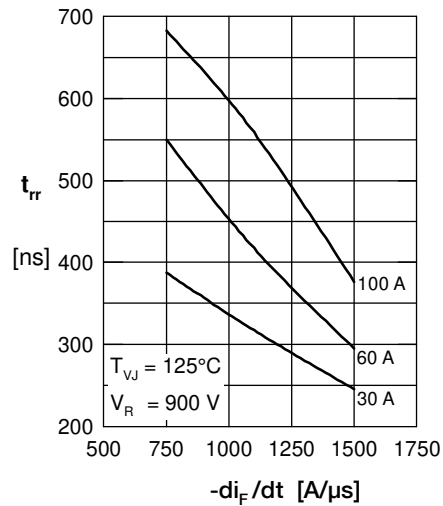
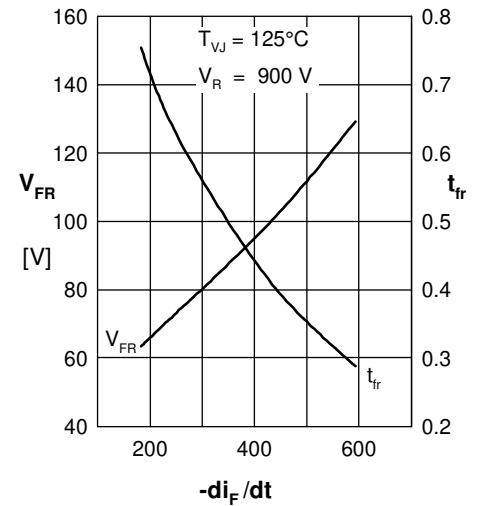
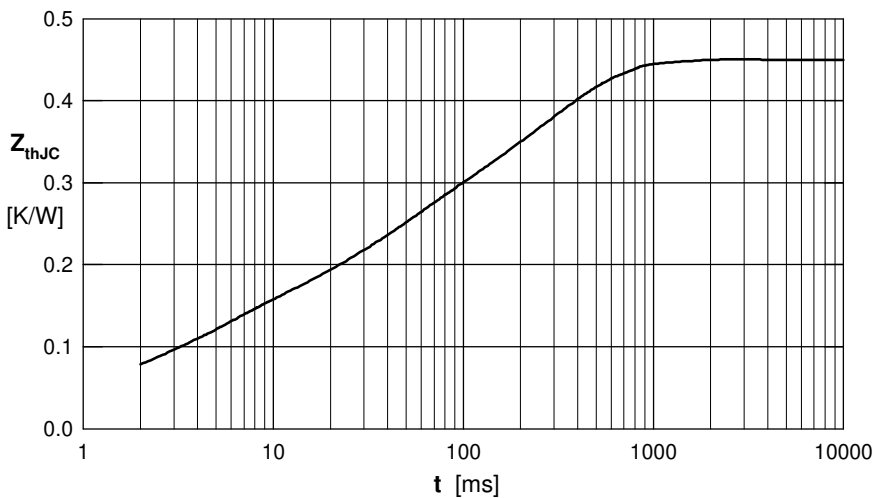
Fast Diode

 Fig. 1 Forward current I_F versus V_F

 Fig. 2 Typ. reverse recovery charge Q_{rr} versus $-di_F/dt$

 Fig. 3 Typ. peak reverse current I_{RM} versus $-di_F/dt$

 Fig. 4 Dyn. parameters Q_r , I_{RM} versus T_{VJ}

 Fig. 5 Typ. recovery time t_{rr} versus $-di_F/dt$

 Fig. 6 Typ. peak forward voltage V_{FR} and t_{fr} versus di_F/dt


Fig. 7 Transient thermal impedance junction to case

 Constants for Z_{thJC} calculation:

| i | R_{th} (K/W) | t_i (s) |
|---|----------------|-----------|
| 1 | 0.033 | 0.0006 |
| 2 | 0.095 | 0.0039 |
| 3 | 1.114 | 0.0330 |
| 4 | 0.208 | 0.2720 |